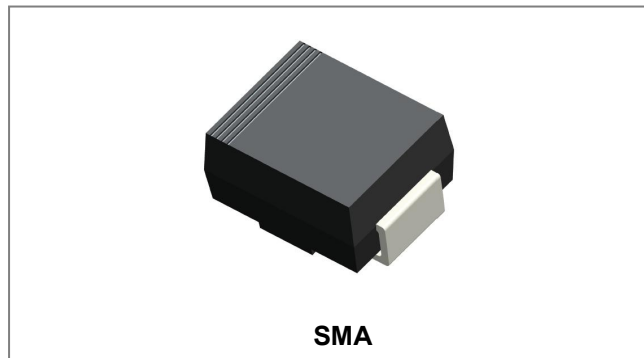


## SK315A SCHOTTKY RECTIFIER



### Features

- Small foot print, surface mountable
- Very low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Green products in compliance the ROHS directive
- This is a Pb - Free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Circuit Diagram



### Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### Maximum Ratings:

| Characteristics                                                                        | Symbol                          | Condition                                                          | Max. | Units |
|----------------------------------------------------------------------------------------|---------------------------------|--------------------------------------------------------------------|------|-------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage | $V_{RRM}$<br>$V_{RWM}$<br>$V_R$ | -                                                                  | 150  | V     |
| Average Rectified Forward Current                                                      | $I_F (AV)$                      | 50% duty cycle @ $T_L = 100^\circ\text{C}$ , rectangular wave form | 3    | A     |
| Peak One Cycle Non-Repetitive Surge Current                                            | $I_{FSM}$                       | 8.3ms, Half Sine pulse, $T_c = 25^\circ\text{C}$                   | 80   | A     |

### Electrical Characteristics:

| Characteristics        | Symbol   | Condition                                                                | Typ.  | Max.   | Units            |
|------------------------|----------|--------------------------------------------------------------------------|-------|--------|------------------|
| Forward Voltage Drop*  | $V_{F1}$ | @ 3A, Pulse, $T_J = 25^\circ\text{C}$                                    | 0.79  | 0.89   | V                |
|                        | $V_{F1}$ | @ 3A, Pulse, $T_J = 125^\circ\text{C}$                                   | 0.65  | 0.79   | V                |
| Reverse Current*       | $I_{R1}$ | @ $V_R = \text{rated } V_R$ , $T_J = 25^\circ\text{C}$                   | 0.003 | 1.0    | mA               |
|                        | $I_{R2}$ | @ $V_R = \text{rated } V_R$ , $T_J = 125^\circ\text{C}$                  | 0.2   | 7.0    | mA               |
| Junction Capacitance   | $C_T$    | @ $V_R = 5\text{V}$ , $T_c = 25^\circ\text{C}$ , $f_{SIG} = 1\text{MHz}$ | 70    | 100    | pF               |
| Series Inductance      | $L_S$    | Measured lead to lead 5 mm from package body                             | 8.0   | -      | nH               |
| Voltage Rate of Change | $dv/dt$  | -                                                                        | -     | 10,000 | V/ $\mu\text{s}$ |

\* Pulse width < 300  $\mu\text{s}$ , duty cycle < 2%

### Thermal-Mechanical Specifications:

| Characteristics                                | Symbol          | Condition    | Specification | Units |
|------------------------------------------------|-----------------|--------------|---------------|-------|
| Junction Temperature                           | $T_J$           | -            | -55 to +150   | °C    |
| Storage Temperature                            | $T_{stg}$       | -            | -55 to +150   | °C    |
| Typical Thermal Resistance Junction to Lead    | $R_{\theta JL}$ | DC operation | 20            | °C/W  |
| Typical Thermal Resistance Junction to Ambient | $R_{\theta JA}$ | DC operation | 77            | °C/W  |
| Approximate Weight                             | wt              | -            | 0.06          | g     |

### Ratings and Characteristics Curves

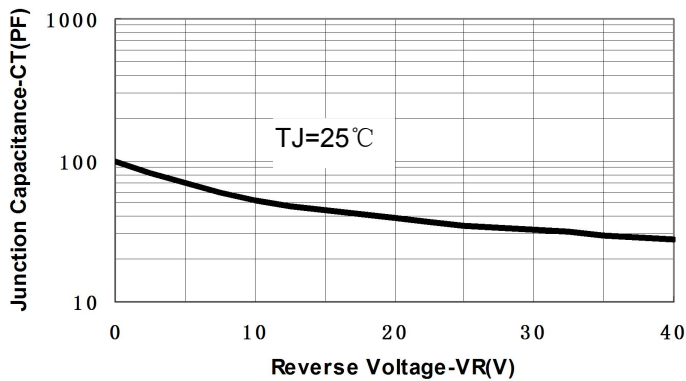


Fig.1-Typical Junction Capacitance

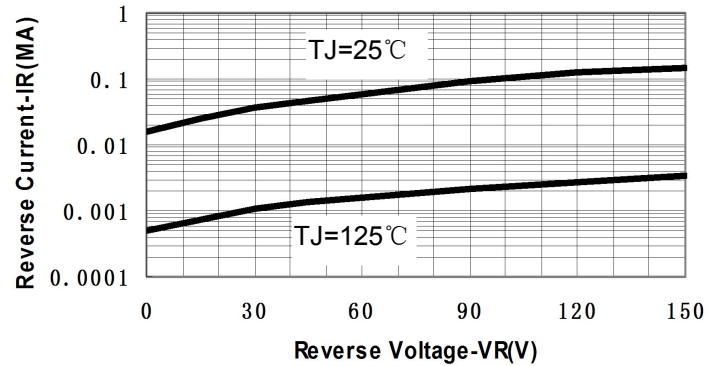


Fig.2-Typical Reverse Characteristics

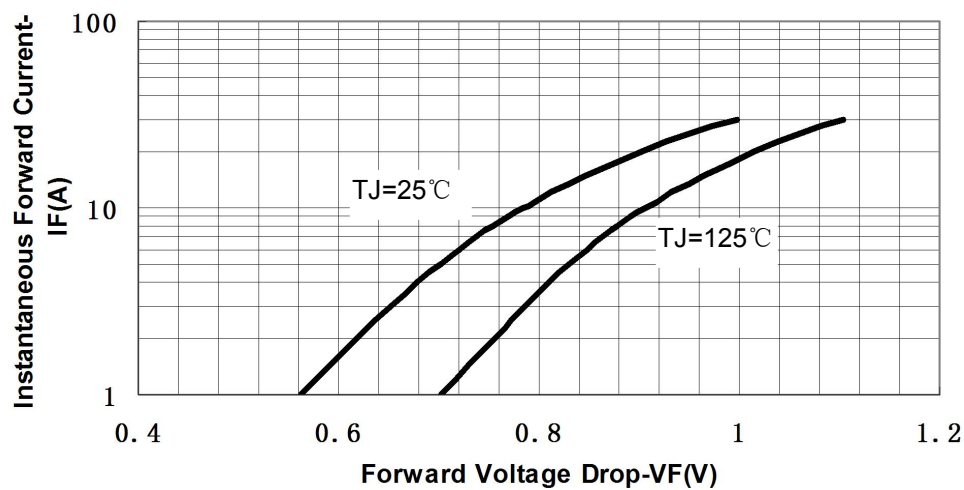
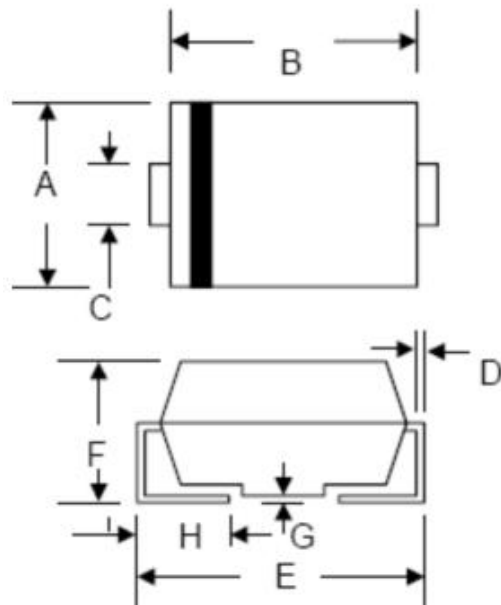


Fig.3-Typical Instantaneous Forward Voltage Characteristics

## Mechanical Dimensions SMA



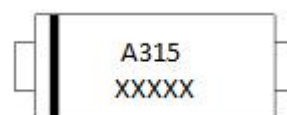
| SYMBOL | Millimeters |       | Inches |       |
|--------|-------------|-------|--------|-------|
|        | Min.        | Max.  | Min.   | Max.  |
| A      | 2.40        | 2.84  | 0.094  | 0.112 |
| B      | 3.99        | 4.75  | 0.157  | 0.187 |
| C      | 1.05        | 1.70  | 0.041  | 0.067 |
| D      | 0.15        | 0.51  | 0.006  | 0.020 |
| E      | 4.80        | 5.66  | 0.189  | 0.223 |
| F      | 1.90        | 2.95  | 0.075  | 0.116 |
| G      | 0.05        | 0.203 | 0.002  | 0.008 |
| H      | 0.76        | 1.52  | 0.030  | 0.600 |

## Ordering Information

| Device | Package          | Shipping       |
|--------|------------------|----------------|
| SK315A | SMA<br>(Pb-Free) | 5000pcs / reel |

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## Marking Diagram

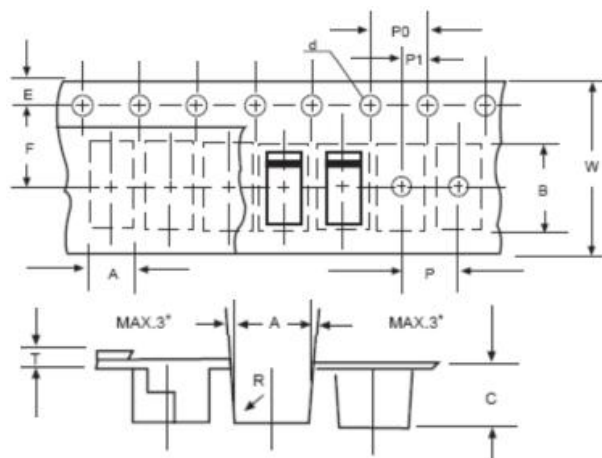


Where XXXXX is YYWWL

A = Package type  
3 = Forward Current (3A)  
15 = Reverse Voltage (150V)  
YY = Year  
WW = Week  
L = Lot Number

**Cautions:** Molding resin  
Epoxy resin UL:94V-0

## Carrier Tape & Reel Specification SMA



| SYMBOL | Millimeters |       |
|--------|-------------|-------|
|        | Min.        | Max.  |
| A      | 2.97        | 3.17  |
| B      | 5.70        | 5.90  |
| C      | 2.32        | 2.52  |
| d      | 1.40        | 1.60  |
| E      | 1.40        | 1.60  |
| F      | 5.60        | 5.70  |
| P      | 3.90        | 4.10  |
| P0     | 3.90        | 4.10  |
| P1     | 1.90        | 2.10  |
| T      | 0.25        | 0.35  |
| W      | 11.80       | 12.20 |

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